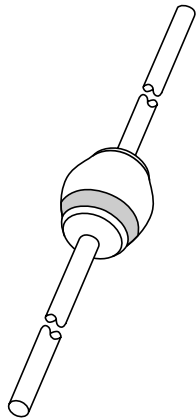


DATA SHEET



BYM56 series Controlled avalanche rectifiers

Product specification
Supersedes data of April 1992

1996 May 24

Controlled avalanche rectifiers

BYM56 series

FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack
- Also available with preformed leads for easy insertion.

DESCRIPTION

Rugged glass package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

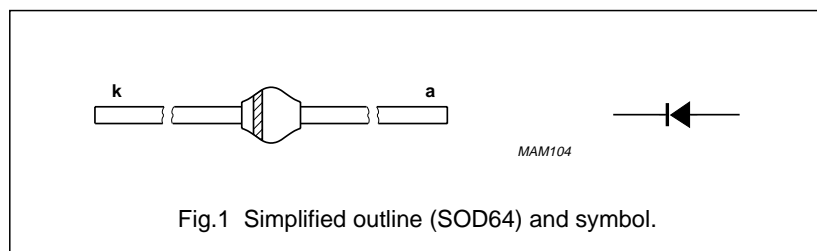


Fig.1 Simplified outline (SOD64) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-------------|-------------------------------------|--|------|------|------|
| V_{RRM} | repetitive peak reverse voltage | | | | |
| | BYM56A | | — | 200 | V |
| | BYM56B | | — | 400 | V |
| | BYM56C | | — | 600 | V |
| | BYM56D | | — | 800 | V |
| | BYM56E | | — | 1000 | V |
| V_{RWM} | crest working reverse voltage | | | | |
| | BYM56A | | — | 200 | V |
| | BYM56B | | — | 400 | V |
| | BYM56C | | — | 600 | V |
| | BYM56D | | — | 800 | V |
| | BYM56E | | — | 1000 | V |
| V_R | continuous reverse voltage | | | | |
| | BYM56A | | — | 200 | V |
| | BYM56B | | — | 400 | V |
| | BYM56C | | — | 600 | V |
| | BYM56D | | — | 800 | V |
| | BYM56E | | — | 1000 | V |
| $I_{F(AV)}$ | average forward current | $T_{tp} = 60\text{ }^{\circ}\text{C}$; lead length = 10 mm; averaged over any 20 ms period; see Figs 2 and 4 | — | 3.5 | A |
| | | $T_{amb} = 65\text{ }^{\circ}\text{C}$; PCB mounting (see Fig.9); averaged over any 20 ms period; see Figs 3 and 4 | — | 1.4 | A |
| I_{FSM} | non-repetitive peak forward current | $t = 10\text{ ms}$ half sinewave; $T_j = T_{j\text{ max}}$ prior to surge; $V_R = V_{RRM\text{ max}}$ | — | 80 | A |

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| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------|--|--|------|------|------|
| E_{RSM} | non-repetitive peak reverse avalanche energy | $L = 120 \text{ mH}$; $T_j = T_{j \text{ max}}$ prior to surge; inductive load switched off | – | 20 | mJ |
| T_{stg} | storage temperature | | –65 | +175 | °C |
| T_j | junction temperature | see Fig.5 | –65 | +175 | °C |

ELECTRICAL CHARACTERISTICS

$T_j = 25 \text{ °C}$; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------|-------------------------------------|---|------|------|------|------|
| V_F | forward voltage | $I_F = 3 \text{ A}$; $T_j = T_{j \text{ max}}$; see Fig.6 | – | – | 0.95 | V |
| | | $I_F = 3 \text{ A}$; see Fig.6 | – | – | 1.15 | V |
| $V_{(BR)R}$ | reverse avalanche breakdown voltage | $I_R = 0.1 \text{ mA}$ | | | | |
| | BYM56A | | 225 | – | – | V |
| | BYM56B | | 450 | – | – | V |
| | BYM56C | | 650 | – | – | V |
| | BYM56D | | 900 | – | – | V |
| | BYM56E | | 1100 | – | – | V |
| I_R | reverse current | $V_R = V_{RRMmax}$; see Fig.7 | – | – | 1 | µA |
| | | $V_R = V_{RRMmax}$; $T_j = 165 \text{ °C}$; see Fig.7 | – | – | 150 | µA |
| t_{rr} | reverse recovery time | when switched from $I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A}$; measured at $I_R = 0.25 \text{ A}$; see Fig.10 | – | 3 | – | µs |
| C_d | diode capacitance | $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$; see Fig.8 | – | 90 | – | pF |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|-----------------------|---|---------------------|-------|------|
| $R_{th \text{ j-tp}}$ | thermal resistance from junction to tie-point | lead length = 10 mm | 25 | K/W |
| $R_{th \text{ j-a}}$ | thermal resistance from junction to ambient | note 1 | 75 | K/W |

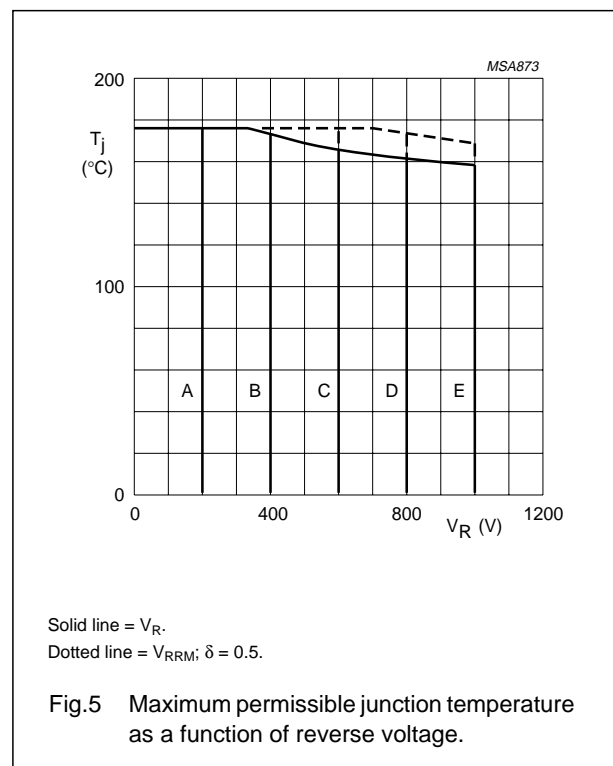
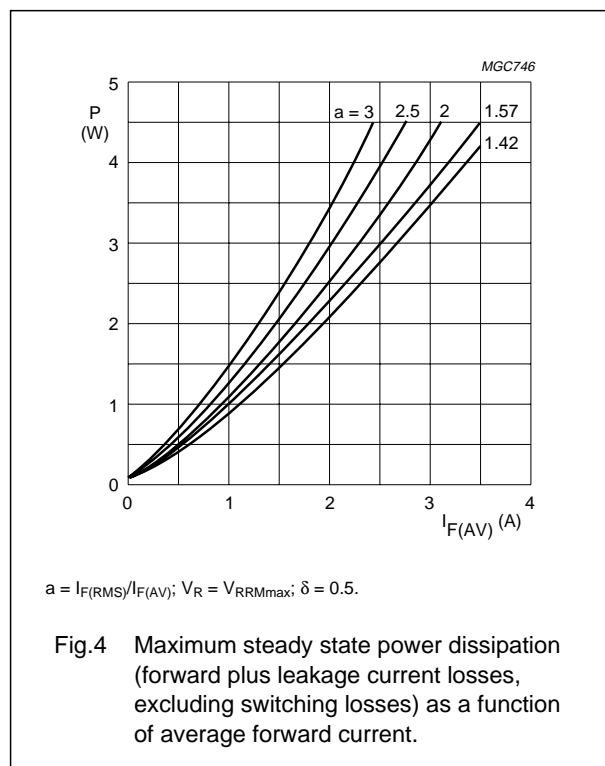
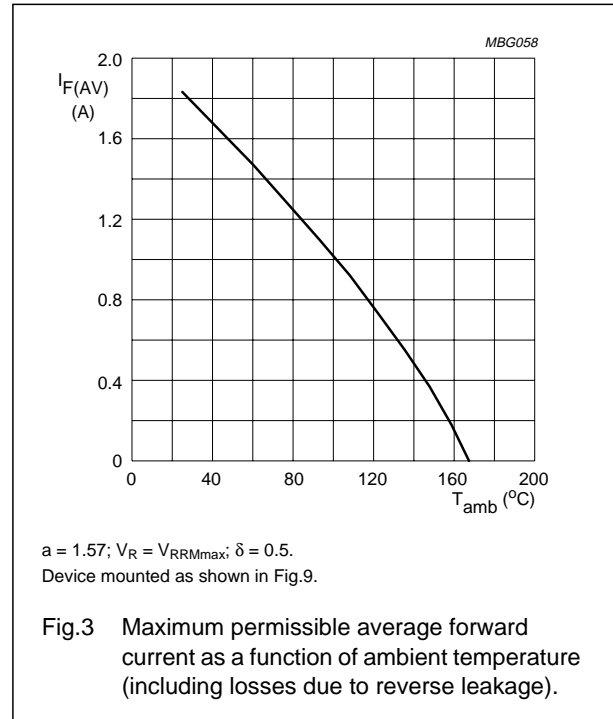
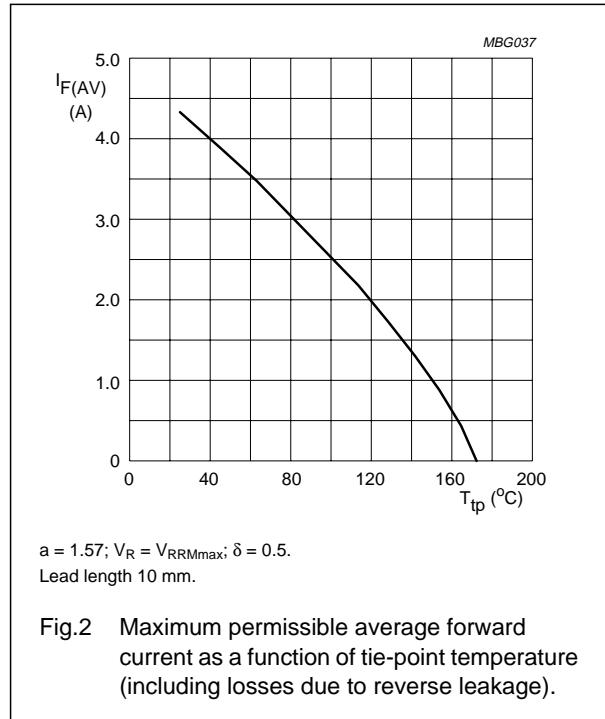
Note

1. Device mounted on epoxy-glass printed-circuit board, 1.5 mm thick; thickness of copper $\geq 40 \text{ µm}$, see Fig.9.
For more information please refer to the "General Part of associated Handbook".

Controlled avalanche rectifiers

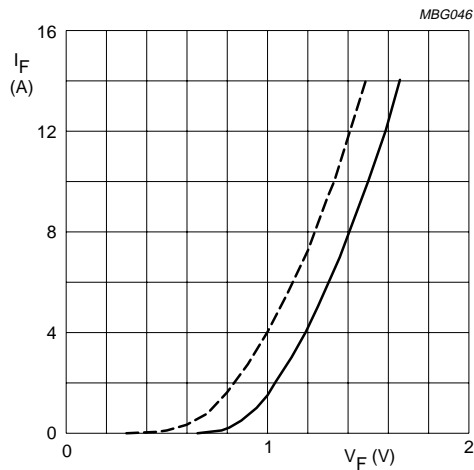
BYM56 series

GRAPHICAL DATA



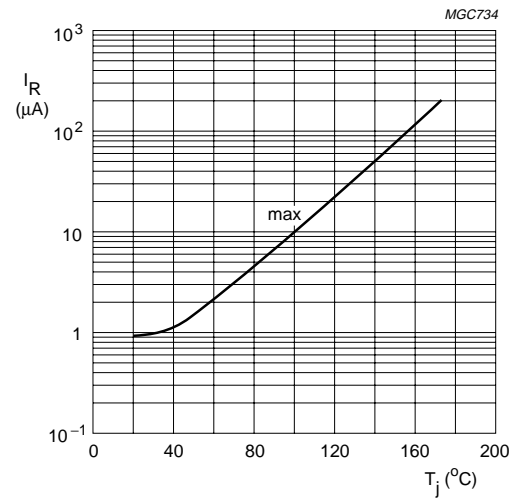
Controlled avalanche rectifiers

BYM56 series



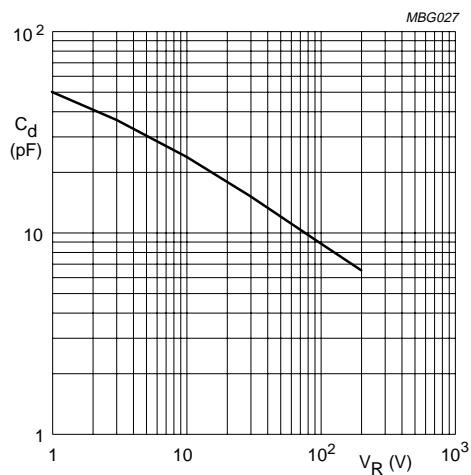
Solid line: $T_j = 25\text{ }^{\circ}\text{C}$.
Dotted line: $T_j = 175\text{ }^{\circ}\text{C}$.

Fig.6 Forward current as a function of forward voltage; maximum values.



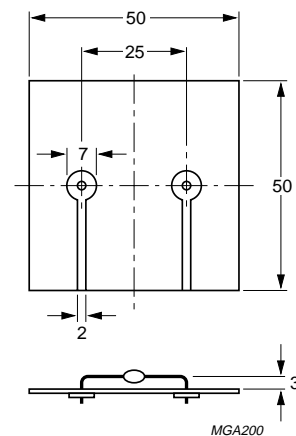
$V_R = V_{RRMmax}$.

Fig.7 Reverse current as a function of junction temperature; maximum values.



$f = 1\text{ MHz}$; $T_j = 25\text{ }^{\circ}\text{C}$.

Fig.8 Diode capacitance as a function of reverse voltage; typical values.

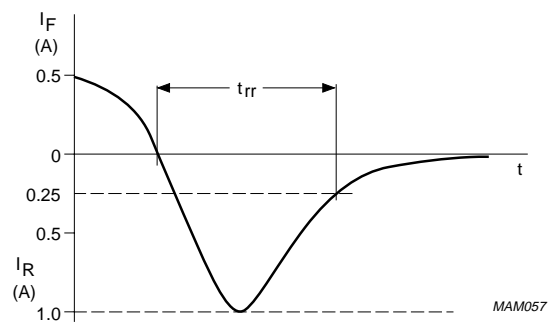
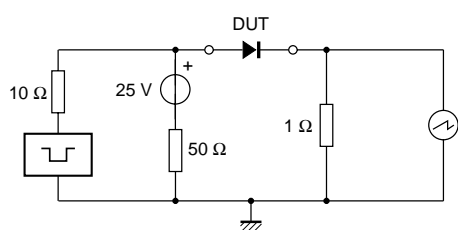


Dimensions in mm.

Fig.9 Device mounted on a printed-circuit board.

Controlled avalanche rectifiers

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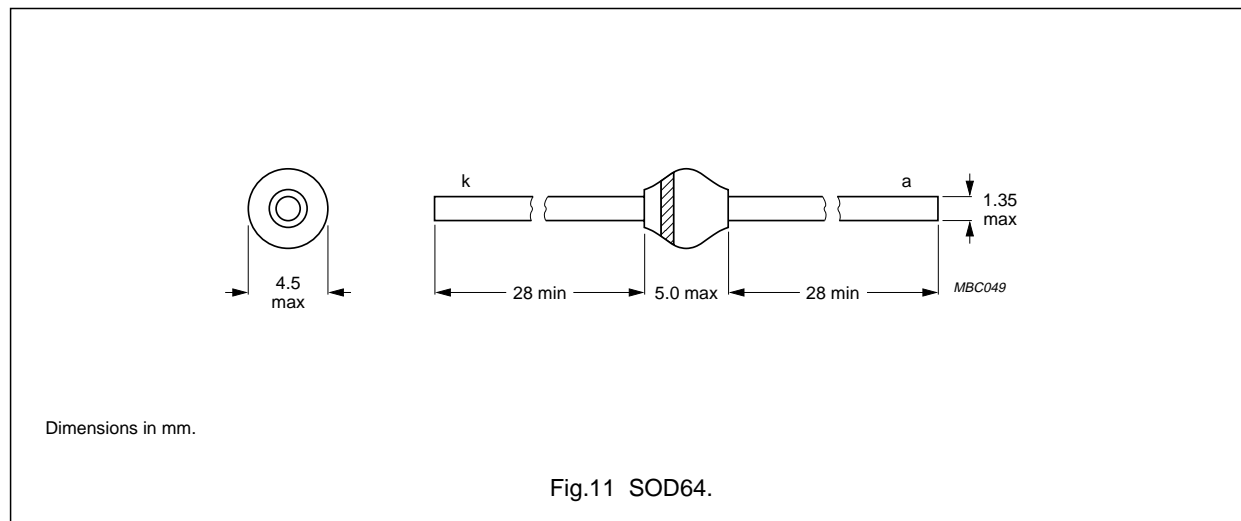
Input impedance oscilloscope: 1 M Ω , 22 pF; $t_r \leq 7$ ns.
Source impedance: 50 Ω ; $t_r \leq 15$ ns.

Fig.10 Test circuit and reverse recovery time waveform and definition.

Controlled avalanche rectifiers

BYM56 series

PACKAGE OUTLINE



LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

DEFINITIONS

| Data sheet status | |
|---|---|
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
| Application information | |
| Where application information is given, it is advisory and does not form part of the specification. | |